## 74LVC245A

## Product Preview

# Low-Voltage CMOS Octal Transceiver 

## With 5 V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The 74LVC245A is a high performance, non-inverting octal transceiver operating from a 1.2 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A $\mathrm{V}_{\mathrm{I}}$ specification of 5.5 V allows 74LVC245A inputs to be safely driven from 5 V devices if $\mathrm{V}_{\mathrm{CC}}$ is less than 5.0 V . The 74LVC245A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at both A and B ports. The Transmit/Receive (T/R) input determines the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

## Features

- Designed for 1.2 to $3.6 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ Operation
- 5 V Tolerant - Interface Capability with 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- $\mathrm{I}_{\mathrm{OFF}}$ Specification Guarantees High Impedance When $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$
- 24 mA Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 $\mu \mathrm{A}$ ) Substantially Reduces System Power Requirements
- Latch-up Performance Exceeds 250 mA
- ESD Performance: Human Body Model >2000 V Machine Model >200 V
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant

[^0]This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

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ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.


Figure 1. Pinout (Top View)

PIN NAMES

| PINS | FUNCTION |
| :--- | :--- |
| $\overline{O E}$ | Output Enable Input |
| T/R | Transmit/Receive Input |
| A0-A7 | Side A 3-State Inputs or 3-State Outputs |
| B0-B7 | Side B 3-State Inputs or 3-State Outputs |

TRUTH TABLE

| INPUTS |  | OPERATING MODE <br> Non-Inverting |
| :---: | :---: | :---: |
| OE | $\mathrm{T} / \mathrm{R}$ |  |
| L | L | A Data to B Bus |
| L | H | Z |
| H | X |  |

[^1]

Figure 2. Logic Diagram

MAXIMUM RATINGS

| Symbol | Parameter | Value | Condition | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $V_{C C}$ | DC Supply Voltage | -0.5 to +6.5 |  | V |
| $V_{1}$ | DC Input Voltage | $-0.5 \leq \mathrm{V}_{1} \leq+6.5$ |  | V |
| $\mathrm{V}_{\mathrm{O}}$ | DC Output Voltage | $-0.5 \leq \mathrm{V}_{\mathrm{O}} \leq+6.5$ | Output in 3-State | V |
|  |  | $-0.5 \leq \mathrm{V}_{\mathrm{O}} \leq \mathrm{V}_{\mathrm{CC}}+0.5$ | Output in HIGH or LOW State (Note 1) |  |
| IIK | DC Input Diode Current | -50 | $\mathrm{V}_{1}<\mathrm{GND}^{\text {d }}$ | mA |
| lok | DC Output Diode Current | -50 | $\mathrm{V}_{\mathrm{O}}<\mathrm{GND}^{\text {d }}$ | mA |
|  |  | +50 | $\mathrm{V}_{\mathrm{O}}>\mathrm{V}_{\mathrm{CC}}$ | mA |
| 10 | DC Output Source/Sink Current | $\pm 50$ |  | mA |
| Icc | DC Supply Current Per Supply Pin | $\pm 100$ |  | mA |
| $\mathrm{I}_{\text {GND }}$ | DC Ground Current Per Ground Pin | $\pm 100$ |  | mA |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range | -65 to +150 |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 Seconds | $\mathrm{T}_{\mathrm{L}}=260$ |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction Temperature Under Bias | $\mathrm{T}_{\mathrm{J}}=135$ |  | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\mathrm{JA}}$ | Thermal Resistance (Note 2) | $\begin{aligned} \hline \text { SOIC } & =65.8 \\ \text { TSSOP } & =110.7 \end{aligned}$ |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| MSL | Moisture Sensitivity |  | Level 1 |  |
| l AATCHUP | Latch-up Performance at $\mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V}$ and $125^{\circ} \mathrm{C}$ (Note 3) |  | $\pm 250$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Io absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm -by-1 inch, 2 ounce copper trace no air flow.
3. Tested to EIA/JES078.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage | Operating Functional | $\begin{gathered} 1.65 \\ 1.2 \end{gathered}$ |  | $\begin{aligned} & 3.6 \\ & 3.6 \end{aligned}$ | V |
| $V_{1}$ | Input Voltage |  | 0 |  | 5.5 | V |
| $\mathrm{V}_{\mathrm{O}}$ | Output Voltage | HIGH or LOW State $3-$ State | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | $\begin{gathered} \hline \mathrm{V}_{\mathrm{cc}} \\ 5.5 \end{gathered}$ | V |
| Іон | HIGH Level Output Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}-3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=2.7 \mathrm{~V}-3.0 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & -24 \\ & -12 \end{aligned}$ | mA |
| loL | LOW Level Output Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}-3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=2.7 \mathrm{~V}-3.0 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 24 \\ & 12 \end{aligned}$ | mA |
| $\mathrm{T}_{\text {A }}$ | Operating Free-Air Temperature |  | -40 |  | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\Delta t / \Delta \mathrm{V}$ | Input Transition Rise or Fall Rate | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=1.2 \text { to } 2.7 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=2.7 \text { to } 3.6 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 10 \end{aligned}$ | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Conditions | -40 to $+85^{\circ} \mathrm{C}$ |  |  | -40 to $+125^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | $\begin{aligned} & \text { Typ } \\ & \text { (Note 4) } \end{aligned}$ | Max | Min | $\begin{gathered} \text { Typ } \\ \text { (Note 4) } \end{gathered}$ | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | HIGH-level input voltage | $\mathrm{V}_{C C}=1.2 \mathrm{~V}$ | 1.08 | - | - | 1.08 | - | - | V |
|  |  | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | $\begin{aligned} & 0.65 x \\ & V_{C C} \end{aligned}$ | - | - | $\begin{gathered} 0.65 x \\ V_{C C} \end{gathered}$ | - | - |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.7 | - | - | 1.7 | - | - |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 3.6 V | 2.0 | - | - | 2.0 | - | - |  |
| VIL | LOW-level input voltage | $\mathrm{V}_{C C}=1.2 \mathrm{~V}$ | - | - | 0.12 | - | - | 0.12 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | - | $\begin{aligned} & 0.35 x \\ & V_{C C} \end{aligned}$ | - | - | $\begin{aligned} & 0.35 x \\ & V_{C C} \end{aligned}$ |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 0.7 | - | - | 0.7 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 3.6 V | - | - | 0.8 | - | - | 0.8 |  |
| $\mathrm{V}_{\mathrm{OH}}$ | HIGH-level output voltage | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ |  |  |  | - | - | - | V |
|  |  | $\begin{gathered} \mathrm{I}_{\mathrm{O}}=-100 \mu \mathrm{~A} ; \\ \mathrm{v}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \end{gathered}$ | $\begin{gathered} v_{\mathrm{CC}}- \\ 0.2 \end{gathered}$ | - | - | $\begin{gathered} \mathrm{v}_{\mathrm{CC}}- \\ 0.3 \end{gathered}$ | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | 1.2 | - | - | 1.05 | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | 1.8 | - | - | 1.65 | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 2.2 | - | - | 2.05 | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-18 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | 2.4 | - | - | 2.25 | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | 2.2 | - | - | 2.0 | - | - |  |
| V OL | LOW-level output voltage | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}}$ |  |  |  | - | - | - | V |
|  |  | $\begin{gathered} \mathrm{I}_{\mathrm{O}}=100 \mu \mathrm{\mu A} ; \\ \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \end{gathered}$ | - | - | 0.2 | - | - | 0.3 |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | - | 0.45 | - | - | 0.65 |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | - | 0.6 | - | - | 0.8 |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 0.4 | - | - | 0.6 |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=-24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | - | 0.55 | - | - | 0.8 |  |
| 1 | Input leakage current | $\begin{gathered} \mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V} \text { or } \mathrm{GND} \\ \mathrm{~V}_{\mathrm{CC}}=3.6 \mathrm{~V} \end{gathered}$ | - | $\pm 0.1$ | $\pm 5$ | - | $\pm 0.1$ | $\pm 20$ | $\mu \mathrm{A}$ |
| Ioz | OFF-state output current | $\begin{gathered} \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} ; \mathrm{V}_{\mathrm{O}}=5.5 \mathrm{~V} \text { or } \\ \mathrm{GND} ; \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \end{gathered}$ | - | $\pm 0.1$ | $\pm 5$ | - | $\pm 0.1$ | $\pm 20$ | $\mu \mathrm{A}$ |
| IofF | Power-off leakage current | $\mathrm{V}_{1}$ or $\mathrm{V}_{\mathrm{O}}=5.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ | - | $\pm 0.1$ | $\pm 10$ | - | $\pm 0.1$ | $\pm 20$ | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Supply current | $\begin{gathered} \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}} \text { or GND; } \mathrm{IO}=0 \mathrm{~A} ; \\ \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \end{gathered}$ | - | 0.1 | 10 | - | 0.1 | 40 | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Additional supply current | $\begin{aligned} & \text { per input pin; } \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}}-0.6 \mathrm{~V} \text {; } \\ & \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \end{aligned}$ | - | 5 | 500 | - | 5 | 5000 | $\mu \mathrm{A}$ |

4. All typical values are measured at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$, unless stated otherwise.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## 74LVC245A

AC ELECTRICAL CHARACTERISTICS $\left(\mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=2.5 \mathrm{~ns}\right)$

| Symbol | Parameter | Conditions | -40 to $+85^{\circ} \mathrm{C}$ |  |  | -40 to $+125^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ <br> (Note 5) | Max | Min | $\begin{array}{\|l\|} \text { Typ } \\ \text { (Note 5) } \end{array}$ | Max |  |
| $\mathrm{t}_{\mathrm{pd}}$ | Propagation Delay (Note 6) An to $\mathrm{Bn}, \mathrm{Bn}$ to An | $\mathrm{V}_{\mathrm{CC}}=1.2 \mathrm{~V}$ | - | 17.0 | - | - | - | - | ns |
|  |  | $\mathrm{V}_{\text {CC }}=1.65 \mathrm{~V}$ to 1.95 V | 1.5 | 6.5 | 14.6 | 1.0 | - | 16.9 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.0 | 3.4 | 7.6 | 1.0 | - | 8.7 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.0 | 3.4 | 7.3 | 1.0 | - | 9.5 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | 1.0 | 2.9 | 6.3 | 1.0 | - | 8.0 |  |
| $\mathrm{t}_{\text {en }}$ | Enable Time (Note 7) $\overline{\mathrm{E}} \mathrm{t}$ to $\mathrm{An}, \mathrm{Bn}$ | $\mathrm{V}_{\mathrm{CC}}=1.2 \mathrm{~V}$ | - | 22.0 | - | - | - | - | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | 1.0 | 8.3 | 19.5 | 1.0 | - | 22.5 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.0 | 4.6 | 10.7 | 1.0 | - | 12.4 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.0 | 4.8 | 9.5 | 0.5 | - | 12.0 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | 0.5 | 3.7 | 8.5 | 0.5 | - | 11.0 |  |
| $t_{\text {dis }}$ | Disable Time (Note 8) $\overline{O E}$ to $\mathrm{An}, \mathrm{Bn}$ | $\mathrm{V}_{\mathrm{CC}}=1.2 \mathrm{~V}$ | - | 12.0 | - | - | - | - | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | 1.0 | 5.5 | 12.3 | 1.0 | - | 14.2 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.0 | 3.1 | 7.1 | 1.0 | - | 8.2 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.0 | 3.9 | 8.0 | 0.5 | - | 10.0 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | 0.5 | 3.6 | 7.0 | 0.5 | - | 9.0 |  |
| $\mathrm{t}_{\text {sk(0) }}$ | Output Skew Time (Note 9) |  | - | - | 1.0 | - | - | 1.5 | ns |

5. Typical values are measured at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$, unless stated otherwise.
6. $t_{p d}$ is the same as $t_{P L H}$ and $t_{P H L}$.
7. $\mathrm{t}_{\mathrm{en}}$ is the same as tpzL and tpzh.
8. $t_{\text {dis }}$ is the same as $t_{P L Z}$ and $t_{P H Z}$.
9. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

## DYNAMIC SWITCHING CHARACTERISTICS

|  | Characteristic | Condition | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol |  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\text {OLP }}$ | Dynamic LOW Peak Voltage (Note 10) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{~V}_{\mathrm{IH}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=2.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=30 \mathrm{pF}, \mathrm{~V}_{\mathrm{IH}}=2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.8 \\ & 0.6 \end{aligned}$ |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {OLV }}$ | Dynamic LOW Valley Voltage (Note 10) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{~V}_{\mathrm{IH}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=2.5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=30 \mathrm{pF}, \mathrm{~V}_{\mathrm{IH}}=2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IL}}=0 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & \hline-0.8 \\ & -0.6 \end{aligned}$ |  | V |

10. Number of outputs defined as " $n$ ". Measured with " $n-1$ " outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

## CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {IN }}$ |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{CC}}$ | 4.0 | pF |
| $\mathrm{C}_{1 / \mathrm{O}}$ | Input/Output Capacitance | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{CC}}$ | 10.0 | pF |
| CPD | Power Dissipation Capacitance (Note 11) | Per input; $\mathrm{V}_{1}=\mathrm{GND}$ or $\mathrm{V}_{\mathrm{CC}}$ |  | pF |
|  |  | $\mathrm{V}_{\text {CC }}=1.65 \mathrm{~V}$ to 1.95 V | 7.7 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 11.3 |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | 14.4 |  |

11. $C_{P D}$ is used to determine the dynamic power dissipation ( $\mathrm{P}_{\mathrm{D}}$ in $\mu \mathrm{W}$ ).
$P_{D}=C_{P D} \times V_{C C}{ }^{2} \times$ fi $\times N+\Sigma\left(C_{L} \times V_{C C}{ }^{2} \times\right.$ fo where:
$\mathrm{fi}=$ input frequency in MHz ; fo $=$ output frequency in MHz
$C_{\mathrm{L}}=$ output load capacitance in pF
$\mathrm{V}_{\mathrm{CC}}=$ supply voltage in Volts
$\mathrm{N}=$ number of outputs switching
$\Sigma\left(C_{L} \times V_{C C}{ }^{2} \times f\right.$ fo $)=$ sum of the outputs.

## 74LVC245A



WAVEFORM 1 - PROPAGATION DELAYS
$t_{R}=t_{F}=2.5 \mathrm{~ns}, 10 \%$ to $90 \% ; f=1 \mathrm{MHz} ; \mathrm{t}_{\mathrm{w}}=500 \mathrm{~ns}$


WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES
$\mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=2.5 \mathrm{~ns}, 10 \%$ to $90 \% ; \mathrm{f}=1 \mathrm{MHz} ; \mathrm{t}_{\mathrm{w}}=500 \mathrm{~ns}$

Figure 3. AC Waveforms

| Symbol | $\mathrm{V}_{\mathbf{C C}}$ |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathbf{1 . 2} \mathbf{V}$ | $\mathbf{1 . 8} \mathrm{V}_{ \pm} \mathbf{0 . 1 5} \mathbf{V}$ | $\mathbf{2 . 5} \mathbf{V} \pm \mathbf{0 . 2} \mathbf{V}$ | $\mathbf{2 . 7} \mathrm{V}$ | $\mathbf{3 . 3} \mathbf{V} \pm \mathbf{0 . 3} \mathbf{V}$ |
|  | $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{CC}}$ | 2.7 V | 2.7 V |
| Vmi | $\mathrm{V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 1.5 V | 1.5 V |
| $\mathrm{Vmo}^{2}$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 1.5 V | 1.5 V |
| $\mathrm{~V}_{\mathrm{HZ}}$ | $\mathrm{V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ |
| $\mathrm{~V}_{\mathrm{LZ}}$ | $\mathrm{V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ |

## 74LVC245A



| Supply Voltage | Input |  | Load |  | $\mathbf{V}_{\mathbf{E X T}}$ |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathbf{V}_{\mathbf{C C}}(\mathbf{V})$ | $\mathbf{V}_{\mathbf{I}}$ | $\mathbf{t}_{\mathbf{r}}, \mathbf{t}_{\mathbf{f}}$ | $\mathbf{C}_{\mathrm{L}}$ | $\mathbf{R}_{\mathrm{L}}$ | $\mathbf{t}_{\text {PLH }}, \mathbf{t}_{\text {PHL }}$ | $\mathrm{t}_{\text {PLZ }}, \mathbf{t}_{\text {PZL }}$ | $\mathbf{t}_{\text {PHZ }}, \mathbf{t}_{\text {PZH }}$ |
| 1.2 | $\mathrm{~V}_{\mathrm{CC}}$ | $\leq 2 \mathrm{~ns}$ | 30 pF | 1 kQ | Open | $2 \times \mathrm{V}_{\mathrm{CC}}$ | GND |
| $1.65-1.95$ | $\mathrm{~V}_{\mathrm{CC}}$ | $\leq 2 \mathrm{~ns}$ | 30 pF | 1 kQ | Open | $2 \times \mathrm{V}_{\mathrm{CC}}$ | GND |
| $2.3-2.7$ | $\mathrm{~V}_{\mathrm{CC}}$ | $\leq 2 \mathrm{~ns}$ | 30 pF | 500 Q | Open | $2 \times \mathrm{V}_{\mathrm{CC}}$ | GND |
| 2.7 | 2.7 V | $\leq 2.5 \mathrm{~ns}$ | 50 pF | 500 Q | Open | $2 \times \mathrm{V}_{\mathrm{CC}}$ | GND |
| $3.0-3.6$ | 2.7 V | $\leq 2.5 \mathrm{~ns}$ | 50 pF | 500 Q | Open | $2 \times \mathrm{V}_{\mathrm{CC}}$ | GND |

Figure 4. Test Circuit

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| 74LVC245ADWR2G | SOIC-20 <br> (Pb-Free) | $1000 /$ Tape \& Reel |
| 74LVC245ADTR2G | TSSOP-20 <br> (Pb-Free) | $2500 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## 74LVC245A

## PACKAGE DIMENSIONS

TSSOP-20
CASE 948E-02
ISSUE C


## PACKAGE DIMENSIONS

SOIC-20
DW SUFFIX
CASE 751D-05
ISSUE G


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR

PROTRUSION. ALLOWABLE PROTRUSION
SHALL BE 0.13 TOTAL IN EXCESS OF B
DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS |  |
| :---: | ---: | ---: |
|  | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| B | 0.35 | 0.49 |
| C | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC |  |
| H | 10.05 | 10.55 |
| $\mathbf{h}$ | 0.25 | 0.75 |
| $\mathbf{L}$ | 0.50 | 0.90 |
| $\boldsymbol{\theta}$ | $0^{\circ}$ | $7^{\circ}$ |

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CY74FCT16245TPVCT 74AHCT245PW. 118 74LV245DB. 118 74LV245D. 112 74LV245PW. 112 74LVC2245APW. 112 74LVCH245AD. 112 SN75138NSR AP54RHC506ELT-R AP54RHC506BLT-R 74LVCR162245ZQLR SN74LVCR16245AZQLR MC100EP16MNR4G MC100LVEP16MNR4G 714100R 74HCT643N MC100EP16DTR2G 5962-9221403MRA 74ALVC164245PAG 74FCT16245ATPAG 74FCT16245ATPVG 74FCT16245ETPAG 74FCT245CTSOG 74LVC162245APAG8


[^0]:    *For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

[^1]:    H = High Voltage Level
    L = Low Voltage Level
    Z = High Impedance State
    X = High or Low Voltage Level and Transitions are Acceptable For ICC reasons, Do Not Float Inputs

